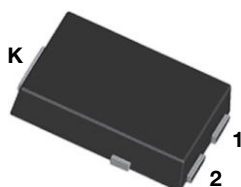
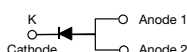


High Current Density Surface Mount Schottky Barrier Rectifier

eSMP® Series



TO-277A (SMPC)



PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	2 x 6.0 A
V_{RRM}	40 V
I_{FSM}	150 A
E_{AS}	20 mJ
V_F at $I_F = 1.0$ A	0.24 V
T_J max.	125 °C

TYPICAL APPLICATIONS

For use in low voltage high frequency inverters, freewheeling, DC/DC converters and polarity protection applications.

FEATURES

- Very low profile - typical height of 1.1 mm
- Ideal for automated placement
- Low forward voltage drop, low power losses
- High efficiency
- Low thermal impedance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- **Halogen-free according to IEC 61249-2-21 definition**

AUTOMOTIVE
GRADE
Available



RoHS
COMPLIANT
HALOGEN
FREE

MECHANICAL DATA

Case: TO-277A (SMPC)

Molding compound meets UL 94 V-0 flammability rating
Base P/N-M3 - halogen-free, RoHS compliant, and commercial grade

Base P/NHM3 - halogen-free, RoHS compliant, and automotive grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test, HM3 suffix meets JESD 201 class 2 whisker test

MAXIMUM RATINGS ($T_A = 25$ °C unless otherwise noted)			
PARAMETER	SYMBOL	SS12P4C	UNIT
Device marking code		S124C	
Maximum repetitive peak reverse voltage	V_{RRM}	40	V
Maximum average forward rectified current (fig. 1) ⁽¹⁾	total device	12	A
	per diode	6.0	
Maximum average forward rectified current ⁽²⁾	total device	3.5	A
Peak forward surge current 10 ms single half sine-wave superimposed on rated load per diode	I_{FSM}	150	A
Non-repetitive avalanche energy at $T_J = 25$ °C, $L = 60$ mH per diode	E_{AS}	20	mJ
Peak repetitive reverse current at $t_p = 2$ μ s, 1 kHz, at $T_J = 25$ °C per diode	I_{RRM}	1.0	A
Operating junction and storage temperature range	T_J, T_{STG}	- 55 to + 125	°C

Notes

(1) Mounted on 30 mm x 30 mm Al PCB with 50 mm x 25 mm x 100 mm fin heat sink

(2) Free air, mounted on recommended copper pad area

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I _F = 1 A	T _A = 25 °C	V _F ⁽¹⁾	0.34	-	V
	I _F = 3 A			0.40	-	
	I _F = 6 A			0.46	0.52	
	I _F = 1 A	T _A = 100 °C		0.24	-	
	I _F = 3 A			0.31	-	
	I _F = 6 A			0.40	0.45	
Reverse current per diode	Rated V _R	T _A = 25 °C	I _R ⁽²⁾	129	500	μA
		T _A = 100 °C		11.9	25	mA
Typical junction capacitance per diode	4.0 V, 1 MHz		C _J	400	-	pF

Notes

- ⁽³⁾ Pulse test: 300 μs pulse width, 1 % duty cycle
- ⁽⁴⁾ Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)			
PARAMETER	SYMBOL	SS12P4C	UNIT
Typical thermal resistance	R _{θJA} ⁽¹⁾	100	°C/W
	R _{θJM} ⁽²⁾	3	

Notes

- ⁽¹⁾ Free air, mounted on recommended copper pad area. Thermal resistance R_{θJA} - junction to ambient.
- ⁽²⁾ Mounted on 30 mm x 30 mm Al PCB with 50 mm x 25 mm x 100 mm fin heat sink. Thermal resistance R_{θJM} - junction to mount.

ORDERING INFORMATION (Example)				
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
SS12P4C-M3/86A	0.10	86A	1500	7" diameter plastic tape and reel
SS12P4C-M3/87A	0.10	87A	6500	13" diameter plastic tape and reel
SS12P4CHM3/86A ⁽¹⁾	0.10	86A	1500	7" diameter plastic tape and reel
SS12P4CHM3/87A ⁽¹⁾	0.10	87A	6500	13" diameter plastic tape and reel

Note

- ⁽¹⁾ Automotive grade

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

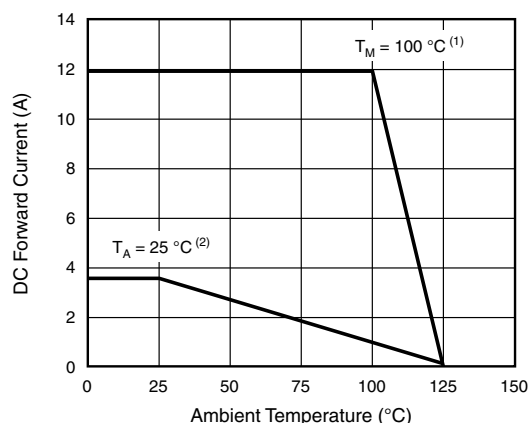


Fig. 1 - Maximum Forward Current Derating Curve

Notes

- ⁽¹⁾ Mounted on 30 mm x 30 mm Al PCB with 50 mm x 25 mm x 100 mm fin heat sink, T_M measured at the terminal of cathode band (R_{θJM} = 3 °C/W)
- ⁽²⁾ Free air, mounted on recommended copper pad area (R_{θJA} = 100 °C/W)

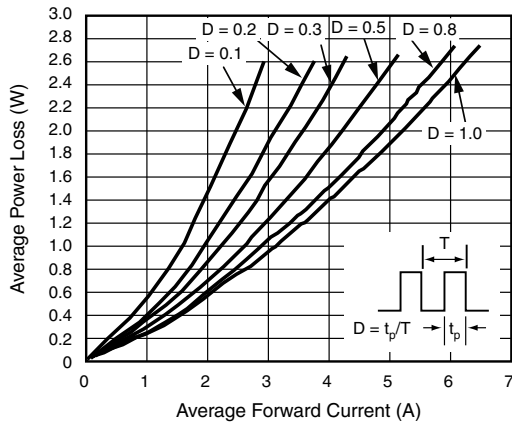


Fig. 2 - Forward Power Loss Characteristics Per Diode

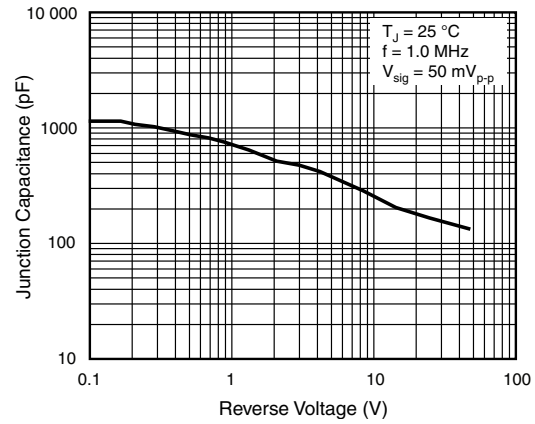


Fig. 5 - Typical Junction Capacitance Per Diode

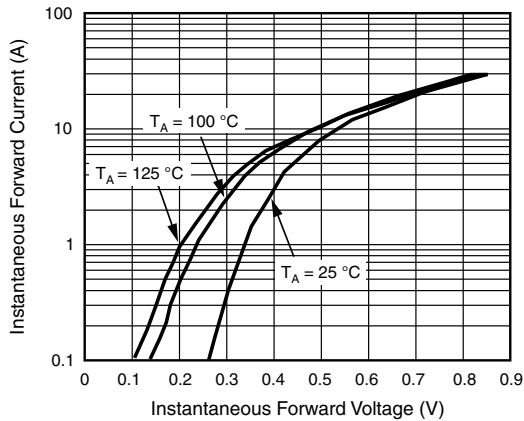


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

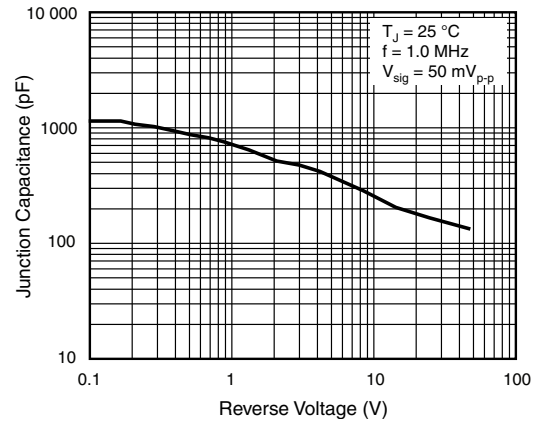


Fig. 6 - Typical Transient Thermal Impedance Per Diode

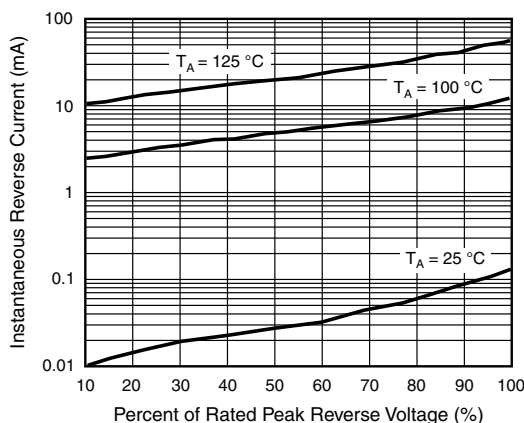


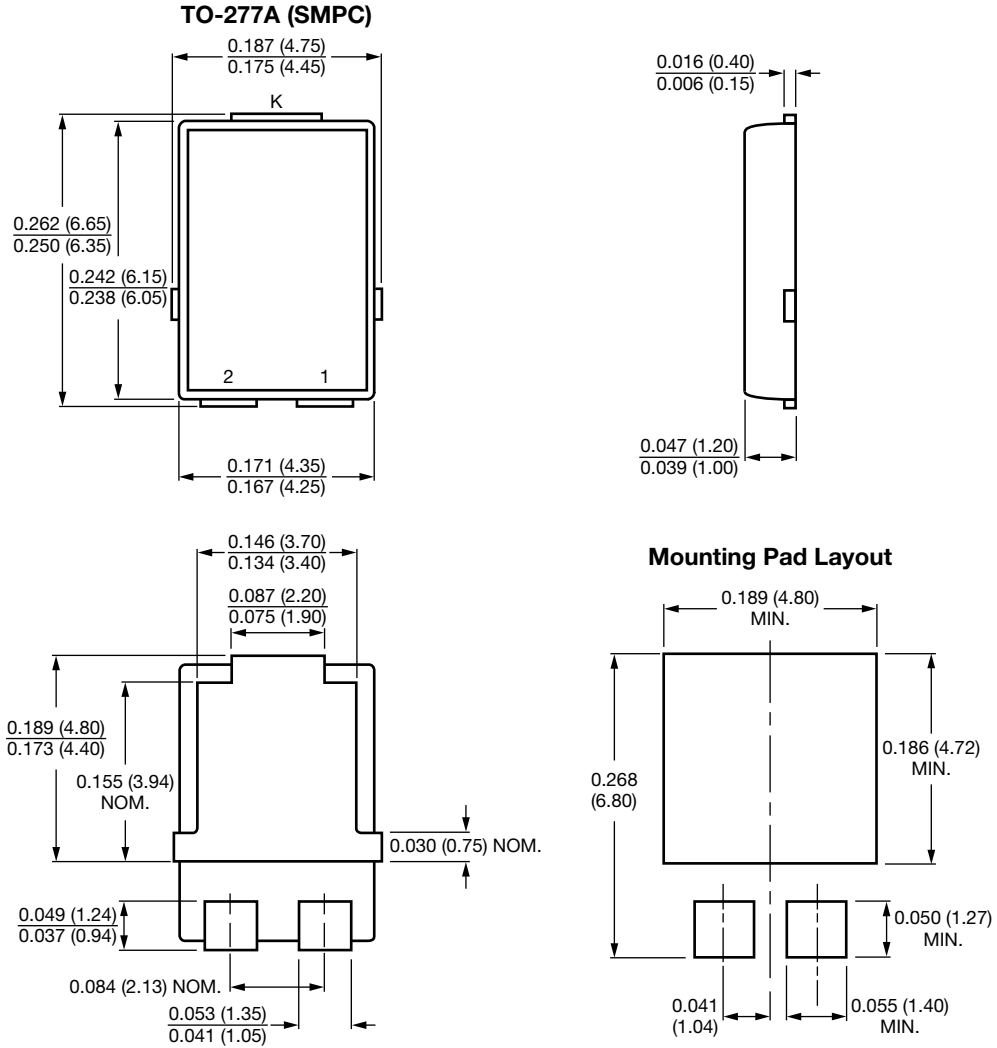
Fig. 4 - Typical Reverse Leakage Characteristics Per Diode

SS12P4C

Vishay General Semiconductor



PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



Conform to JEDEC TO-277A



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